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24096 .00500Serial No.
09/697,203

INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

Applicant

Kozlowski, Lester J..

Filing Date

October 26, 2000

Group

2878

U.S. PATENT DOCUMENTS

*Examine r Initials		Document Number	Date	Name	Class	Subclass	Filing Date
if	AA	Re 34,908	9/5/00	Wyles, et al			
if	AB	4,249,122	2/3/81	Widlar			
if	AC	4,463,383	7/31/84	Sonoda, et al			
if	AD	4,466,018	8/14/84	Sonoda, et al			
if	AE	4,676,761	6/30/87	Poujois			
if	AF	4,794,247	12/27/88	Stineman, et al			
if	AG	5,043,820	8/27/91	Wyles, et al			
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if	AI	5,345,266	9/6/94	Denyer, et al			
if	AJ	5,296,696	3/22/94	Uno, M.			
if	AK	5,471,515	11/28/95	Fossum, et al			
if	AL	5,576,763	11/19/96	Ackland, et al			
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if	AS	5,382,977	1/17/95	Kozlowski, et al			
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y	BD	J.D. Plummer and J.D. Meindl, "MOS Electronics For A portable Reading Aid For The Blind", IEEE J. Solid-State Circuits, SC-7, April 1972, pp. 111-119
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y	BG	EG&G Reticon Sales Catalog, Image Sensing and Solid State Camera Products 1994/1995. Solid State Image Sensor Array Specification For Part No: RA0256B
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y	BK	N. Tanaka, T. Ohmi and Y. Nakamura, "A Novel Bipolar Imaging Device With Self-Noise Reduction Capability", IEEE Trans. Elec. Dev., 36 (1), January 1989, pp. 31-38
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y	BM	N. Tanaka, T. Ohmi, Y. Nakamura and S. Matsumoto, "A Low-Noise Bi-CMOS Linear Imager Sensor With Auto-Focusing Function", IEEE Trans. Elec. Dev., 36 (1), January 1989, pp. 39-45
y	BN	N. Tanaka, S. Hashimoto, M. Shinohara, S. Sugawa, m. Morishita, S. Matsumora, Y. Nakamura and T. Ohmi, "A 310k Pixel Bipolar Imager (BASIS), ISSCC 1989
y	BO	G.P. Weckler, "Charge Storage Lights The Way For Solid-State Image Sensors", Electronics, May 1, 1967, pp. 75-78
y	BP	G.P. Weckler, "Operation of p-n Junction Photodetectors In A Photon Flux Integrating Mode", IEEE Journal Of solid State Circuits, Vol. SC-2, No. 3, September 1967, pp. 65-73
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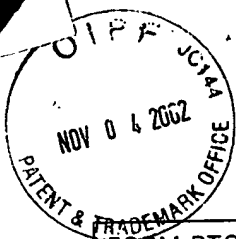


uf.	BV	Letter Dated July 31, 1998, From Gene Weckler, RAD-ICON IMAGING CORP., addressed to Mark Wettler
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Examiner 		Date Considered 3/19/04
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*Examine Initials		Document Number	Date	Name	Class	Subclass	Filing Date
<i>ly</i>	AA	6,243,134	06/05/01	Beiley			02/27/98
<div style="text-align: center;">RECEIVED NOV 07 2002 Technology Center 2600</div> <div style="text-align: right; transform: rotate(-90deg);">TC 2800 MAIL ROOM NOV - 5 2002 RECEIVED</div>							
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		Document Number	Date	Country	Class	Subclass	Translation Yes No
OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)							
<i>ly</i>	AB	Copy of International Search Report					
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